



Package Style: QFN, 16-Pin, 0.9mm x 3mm x 3mm

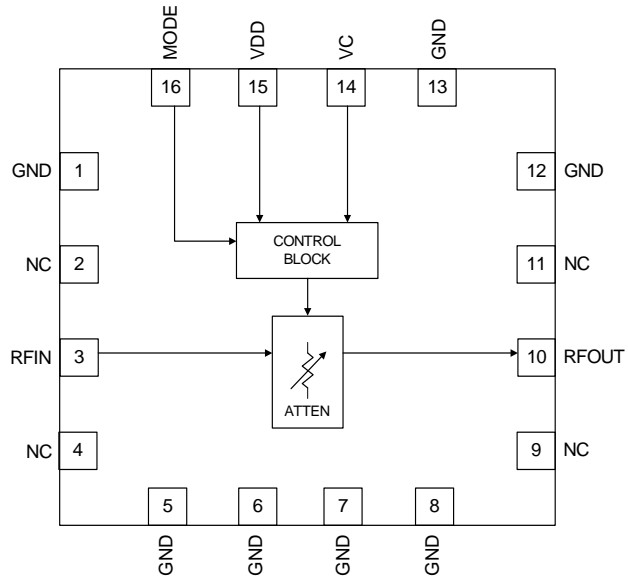


Features

- Patent Pending Circuit Architecture
- Broadband 50MHz to 6000MHz Frequency Range
- 30dB Attenuation Range
- +50dBm IIP3 Typical
- +80dBm IIP2 Typical
- High 1dB Compression Point >+30dBm
- Low Supply Current 1mA Typical
- 5V Power Supply
- Linear in dB Control Characteristic
- Internal Temperature Compensation
- Class 1C ESD (1000V)
- 3.3V Version Available (RFSA2023)
- Complete Solution in a Small 3mm x 3mm, QFN Package

Applications

- Cellular, 3G Infrastructure
- WiBro, WiMax, LTE
- Microwave Radio
- High Linearity Power Control



Functional Block Diagram

Product Description

RFMD's RFSA2013 is a fully monolithic analog voltage controlled attenuator (VCA) featuring exceptional linearity over a typical temperature compensated 30dB gain control range. It incorporates a revolutionary new circuit architecture to solve a long standing industry problem: high IP3, high attenuation range, low DC current, broad bandwidth and temperature compensated linear in dB control voltage characteristic. This voltage controlled attenuator is controlled by a single positive control voltage with on chip DC conditioning circuitry. The slope of the control voltage versus gain is selectable. The RFSA2013 draws a very low 1mA current and is packaged in a small 3mm x 3mm QFN. This attenuator is matched to 50Ω over its rated control range and frequency with no external matching components required. Typical VCA's in this performance category have poor inherent attenuation versus temperature and poor nonlinear attenuation versus control voltage characteristics. To correct these shortcomings, other VCA's require extensive off chip analog support circuitry that consume valuable PCB area and additional DC power. This game changing product incorporates the complete solution in a small 3mm x 3mm QFN package that reduces the footprint by 20X in area and reduces the DC power by 10X over conventional PIN diode approaches.

Ordering Information

RFSA2013SR	7" Sample reel with 100 pieces
RFSA2013SQ	Sample bag with 25 pieces
RFSA2013TR7	7" Reel with 2500 pieces
RFSA2013PCK-410	50MHz to 6000MHz PCBA with 5-piece sample bag

Optimum Technology Matching® Applied

- | | | | |
|--------------------------------------|--------------------------------------|---|------------------------------------|
| <input type="checkbox"/> GaAs HBT | <input type="checkbox"/> SiGe BiCMOS | <input type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT |
| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS | <input checked="" type="checkbox"/> Si CMOS | <input type="checkbox"/> BiFET HBT |
| <input type="checkbox"/> InGaP HBT | <input type="checkbox"/> SiGe HBT | <input type="checkbox"/> Si BJT | |

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V_{DD})	-0.5 to +6	V
Control Voltage (V_C)	-0.5 to +6	V
Mode Pin Voltage (MODE)	-0.5 to +6	V
RF Input Power	+30	dBm
Operating Temperature	-40 to +85	°C
Storage Temperature	-65 to +150	°C
Junction Temperature	+125	°C
ESD Rating Human Body Model (HBM)	1000	V



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

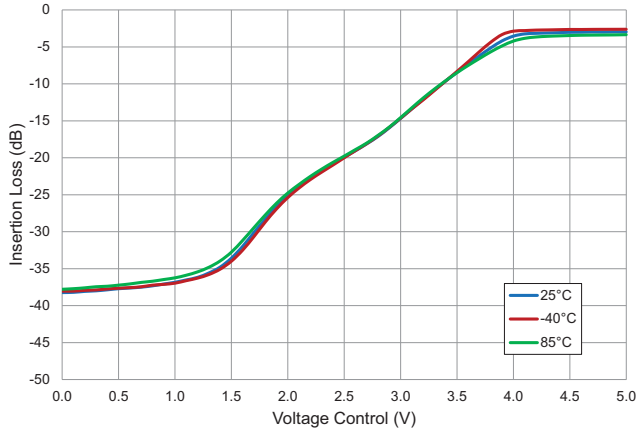
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
General					
Supply Voltage	4.75	5	5.25	V	
Supply Current		1		mA	
Operating Temperature	-40		85	°C	
Thermal Resistance		45		°C/W	RF input must be RFIN pin
RF Input Power			27	dBm	RF input must be RFIN pin
RF Performance					
Frequency Range	50		6000	MHz	
Minimum Insertion Loss		2.6	3.5	dB	
Gain Control Range	30	33.2		dB	DC to 4GHz
Gain versus Temperature		1.7		dB	Peak to peak gain variation over temperature for fixed control voltage
Return Loss		15		dB	
Relative Phase		16.2		Deg	Insertion phase at 15dB attenuation relative to minimum insertion loss
Input 1dB Compression Point		30		dBm	
Input IP3	45	50		dBm	PIN + (IM3 _{dB} /2)
Input IP2		80		dBm	PIN + IM2 _{dB} , IM2 is F1+F2
Input IH2		85		dBm	PIN + H2 _{dB} , H2 is second harmonic
Input IH3		55		dBm	PIN + (H3 _{dB} /2), H3 is third harmonic
Control					
Voltage Control Range, Positive Attenuation Slope	0.5		4.5	V	4.5V control voltage is lowest insertion loss, MODE pin high
Voltage Control Range, Negative Attenuation Slope	0		3.3	V	0V control voltage is lowest insertion loss, MODE pin low
Voltage Control Pin Current (MODE High)		37		µA	VC Pin at 5V
Voltage Control Pin Current (MODE Low)		24		µA	VC Pin at 3.3V
MODE Pin Logic Low			0.4	V	
MODE Pin Logic High	1			V	
Settling Time		15		µsec	1dB attenuation change settling within 0.1dB

Note: Typical performance at nominal conditions unless otherwise noted: Supply voltage = 5.0V, Operating temperature = 25 °C, RF Frequency 2GHz

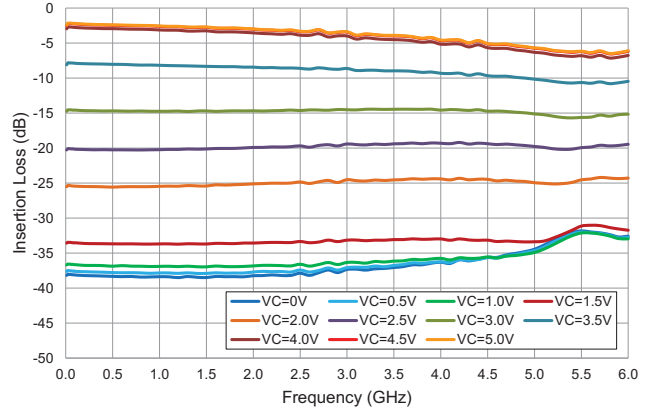
Measured Positive Attenuation Slope Performance

Data includes PCB and connector losses

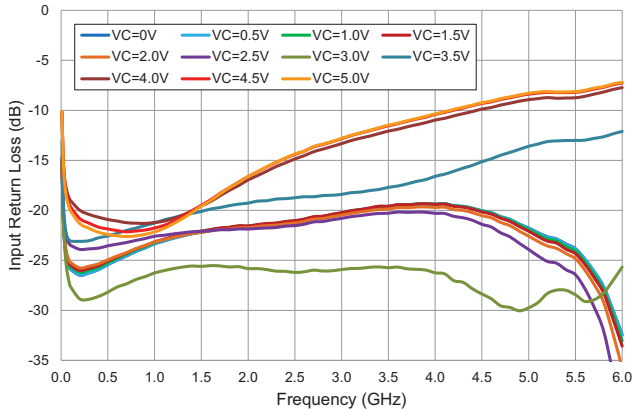
Insertion Loss versus Voltage Control
RF 2GHz, V_{DD}=5V



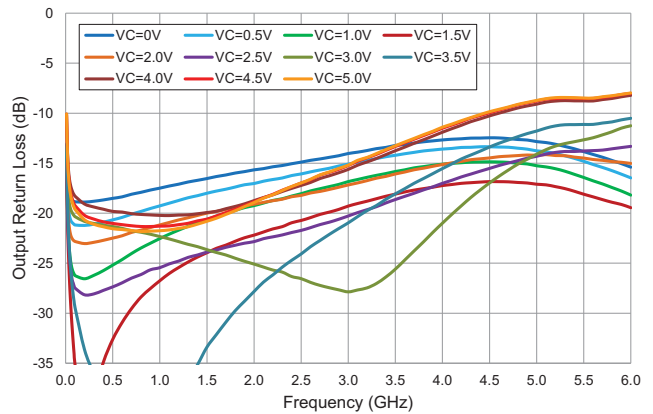
Insertion Loss versus Frequency
V_{DD}=5V, Temp=+25°C



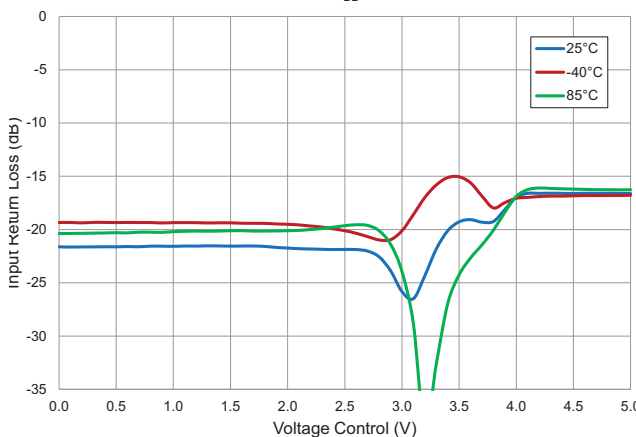
Input Return Loss versus Frequency
V_{DD}=5V, Temp=+25°C



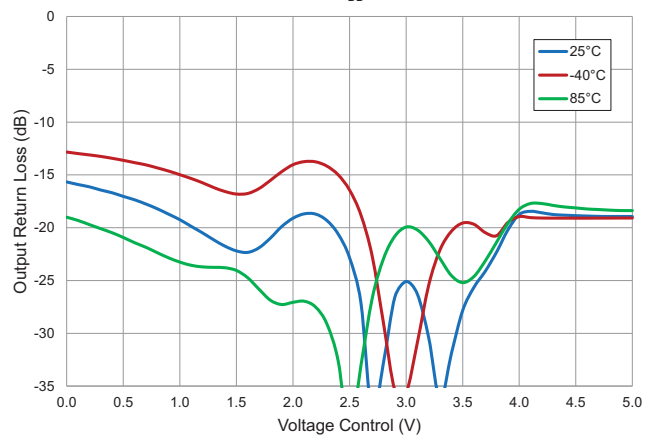
Output Return Loss versus Frequency
V_{DD}=5V, Temp=+25°C



Input Return Loss versus Voltage Control
RF 2GHz, V_{DD}=5V



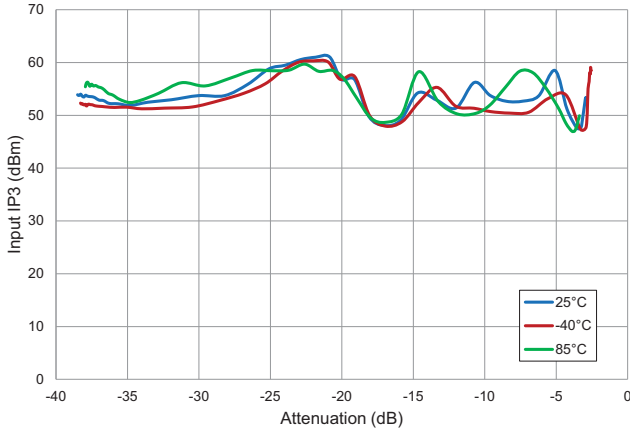
Output Return Loss versus Voltage Control
RF 2GHz, V_{DD}=5V



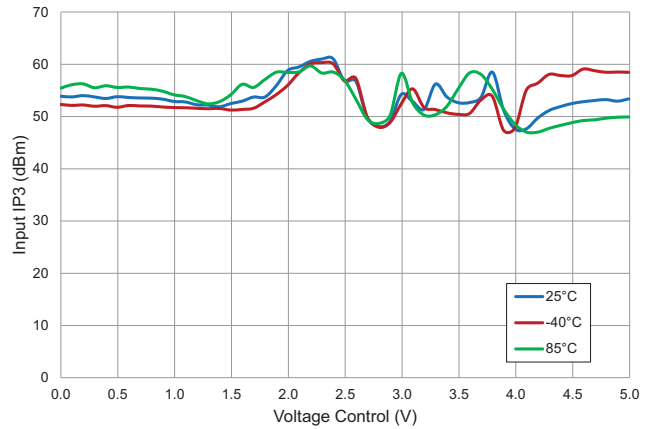
Measured Positive Attenuation Slope Performance

Data includes PCB and connector losses

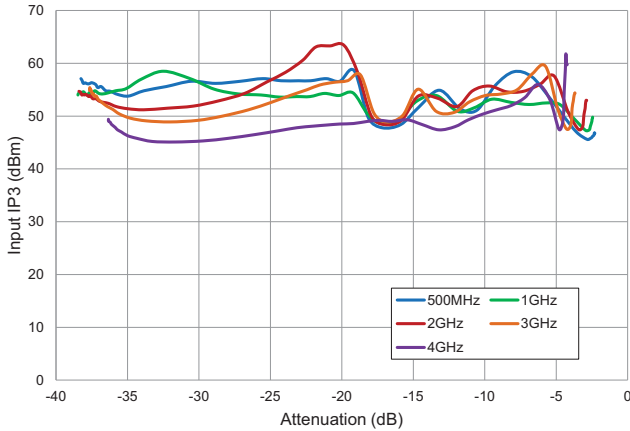
Input IP3 versus Attenuation
RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm/Tone$



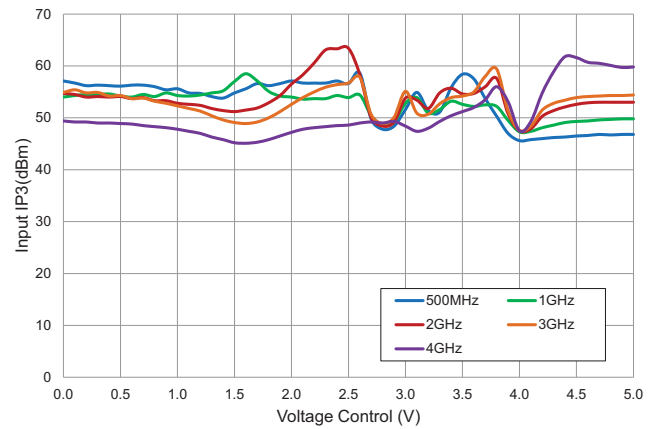
Input IP3 versus Voltage Control
RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm/Tone$



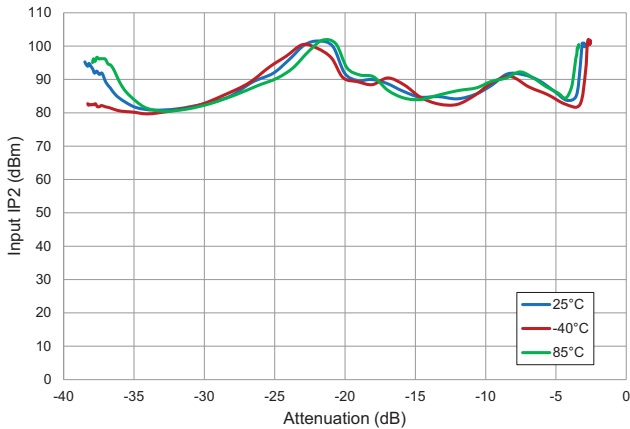
Input IP3 versus Attenuation
 $V_{DD}=5V$, $P_{in}=+20dBm/Tone$, Temp= $+25^{\circ}C$



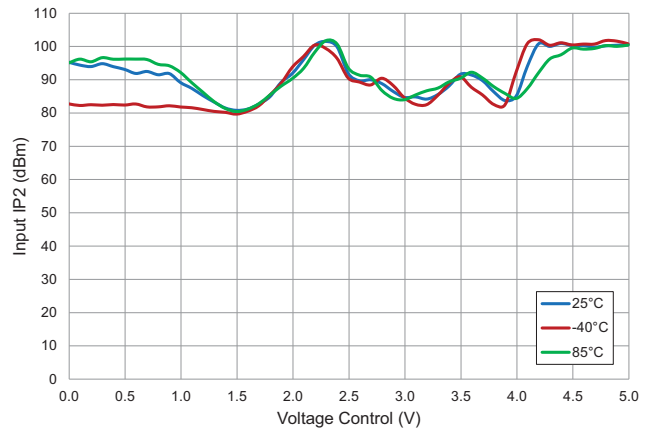
Input IP3 versus Voltage Control
 $V_{DD}=5V$, $P_{in}=+20dBm/Tone$, Temp= $+25^{\circ}C$



Input IP2 versus Attenuation
RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm/Tone$

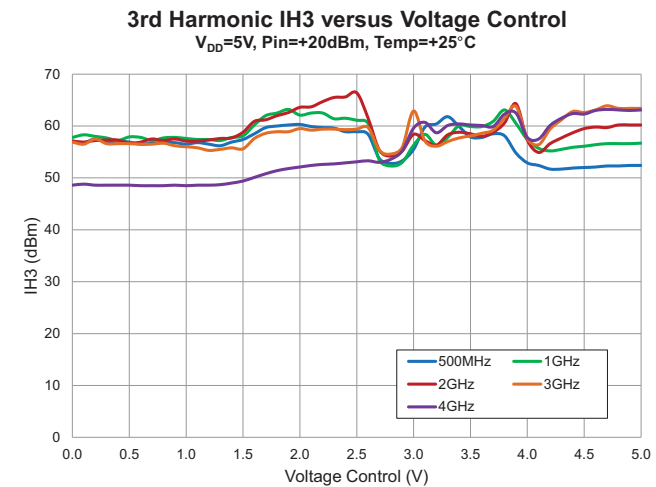
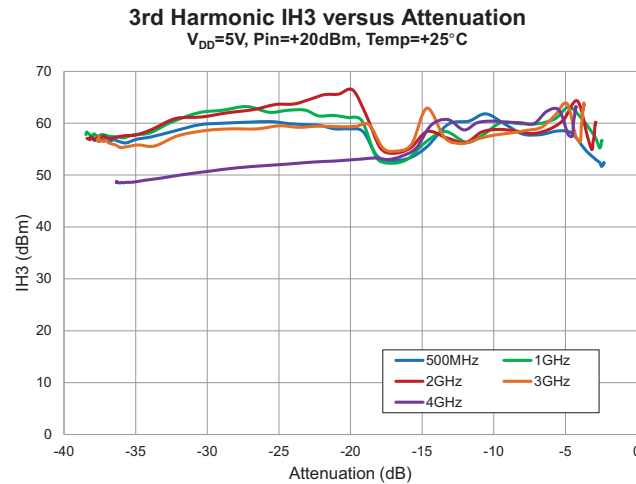
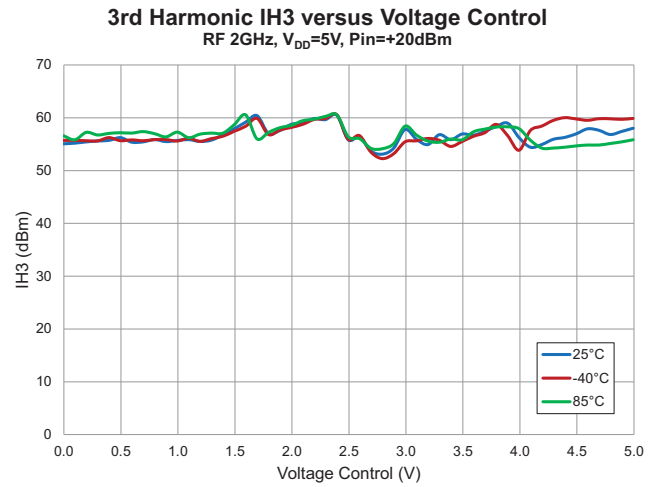
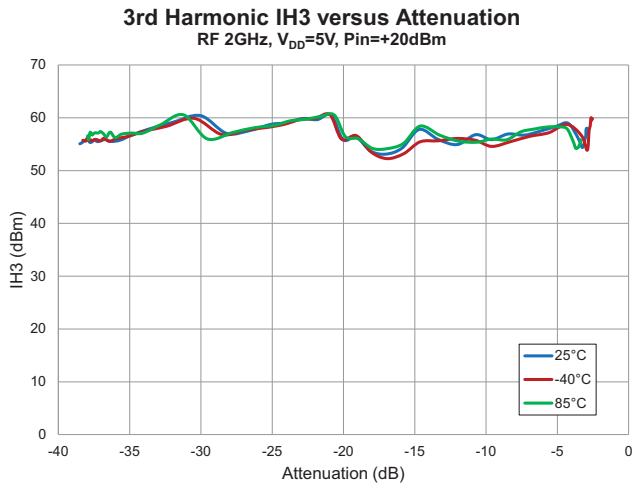
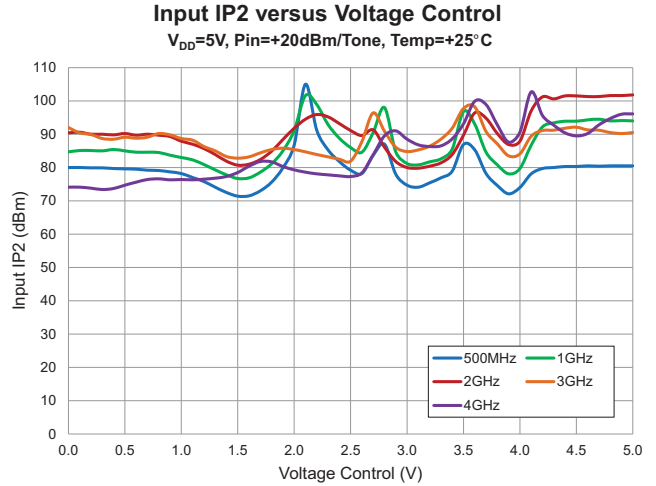
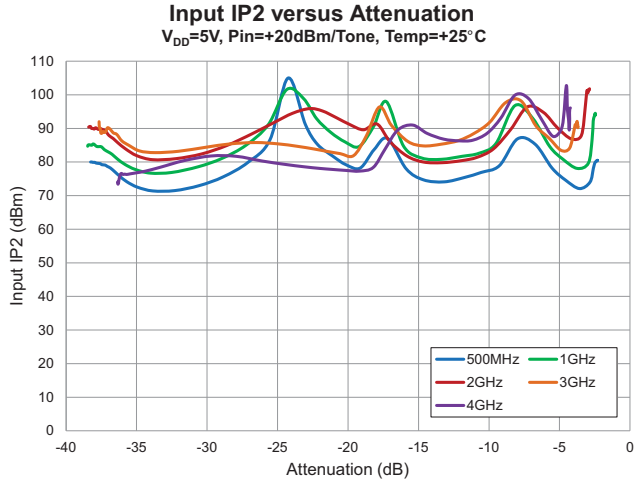


Input IP2 versus Voltage Control
RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm/Tone$



Measured Positive Attenuation Slope Performance

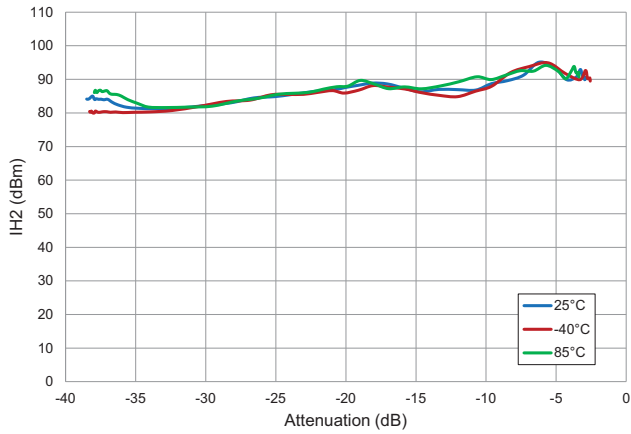
Data includes PCB and connector losses



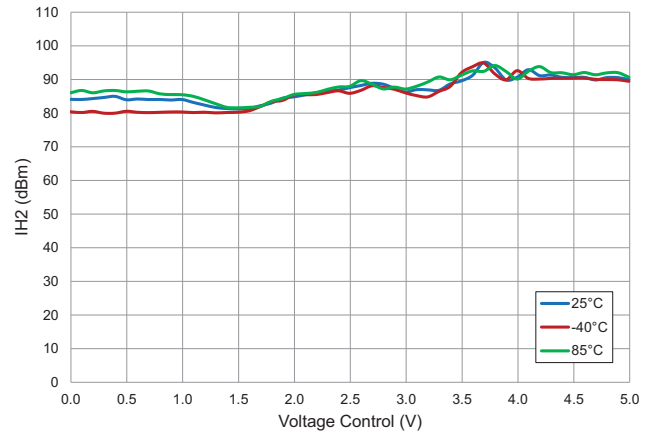
Measured Positive Attenuation Slope Performance

Data includes PCB and connector losses

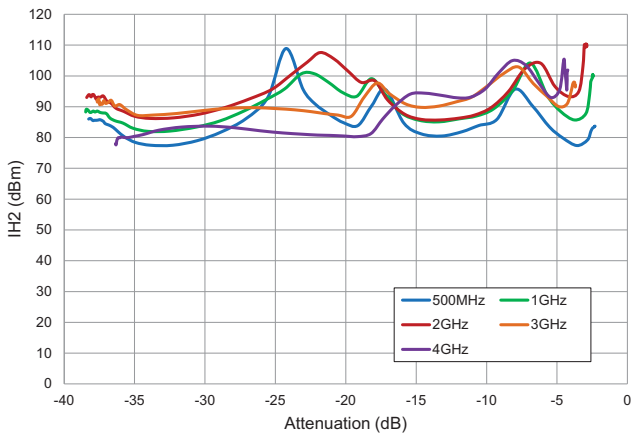
2nd Harmonic IH2 versus Attenuation
RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm$



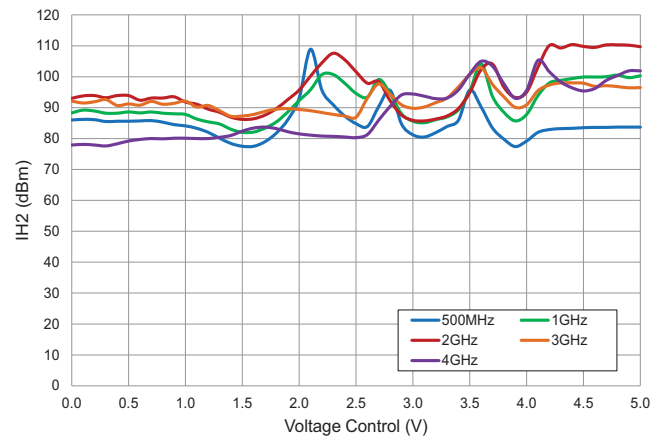
2nd Harmonic IH2 versus Voltage Control
RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm$



2nd Harmonic IH2 versus Attenuation
 $V_{DD}=5V$, $P_{in}=+20dBm$, Temp= $+25^\circ C$



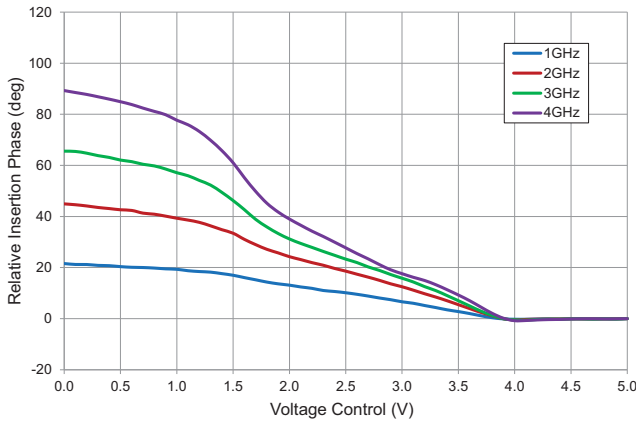
2nd Harmonic IH2 versus Voltage Control
 $V_{DD}=5V$, $P_{in}=+20dBm$, Temp= $+25^\circ C$



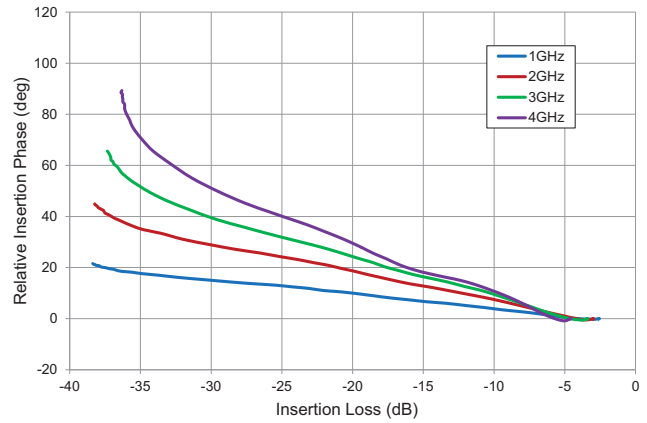
Measured Positive Attenuation Slope Performance

Data includes PCB and connector losses

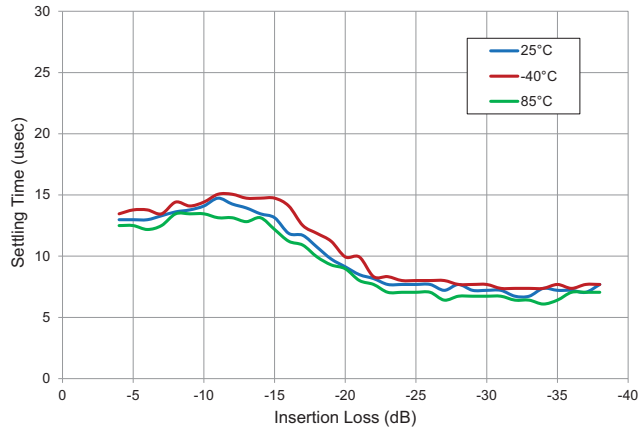
Relative Insertion Phase versus Voltage Control
 $V_{DD}=5V$, Temp= $+25^{\circ}C$



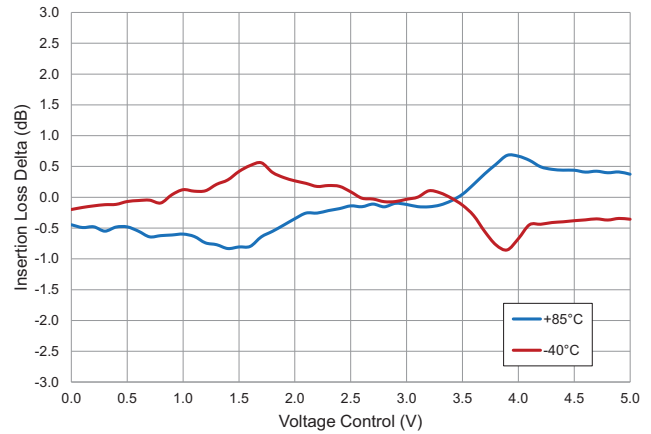
Relative Insertion Phase versus Insertion Loss
 $V_{DD}=5V$, Temp= $+25^{\circ}C$



Settling Time versus Insertion Loss
 1dB Steps, RF 2GHz, $V_{DD}=5V$



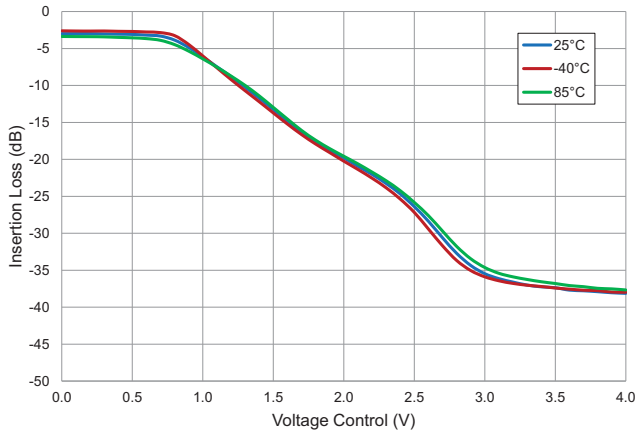
Insertion Loss Relative to +25°C
 RF 2GHz, $V_{DD}=5V$



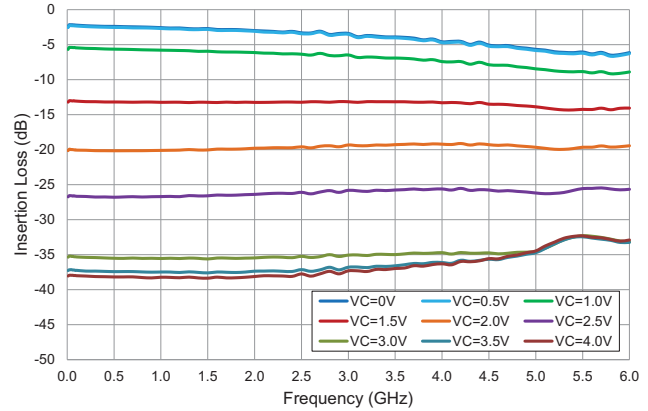
Measured Negative Attenuation Slope Performance

Data includes PCB and connector losses

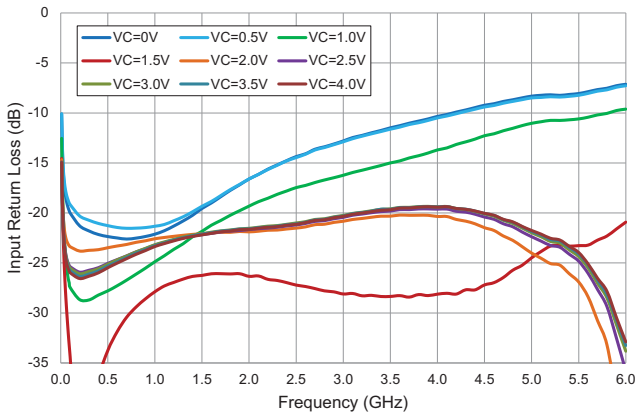
Insertion Loss versus Voltage Control
RF 2GHz, $V_{DD}=5V$



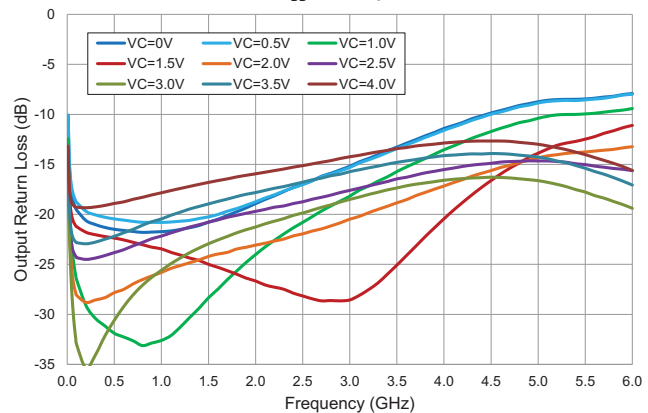
Insertion Loss versus Frequency
 $V_{DD}=5V$, Temp=+25°C



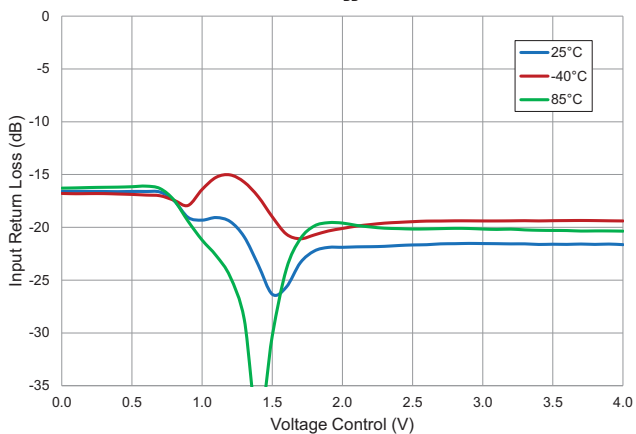
Input Return Loss versus Frequency
RF 2GHz, $V_{DD}=5V$, Temp=+25°C



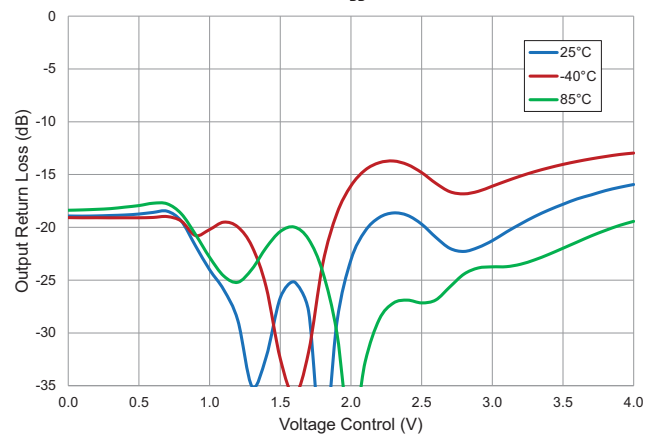
Output Return Loss versus Frequency
RF 2GHz, $V_{DD}=5V$, Temp=+25°C



Input Return Loss versus Voltage Control
RF 2GHz, $V_{DD}=5V$

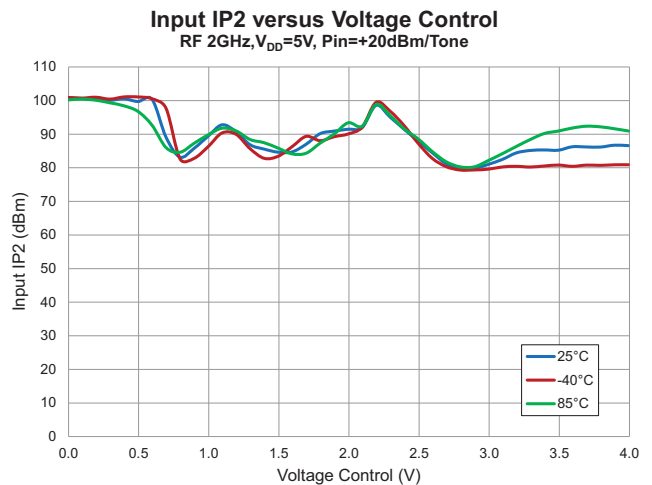
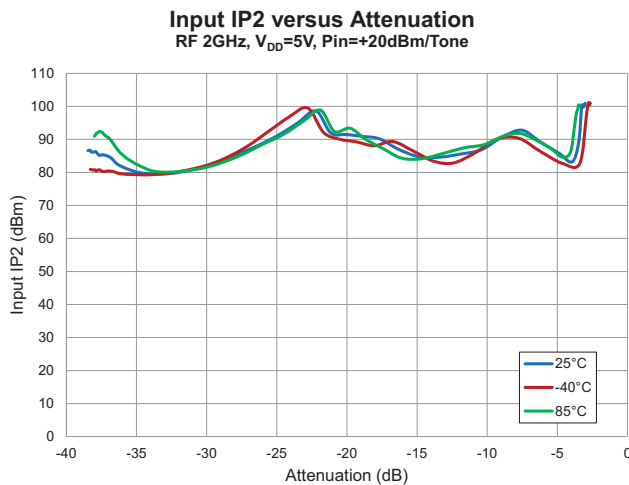
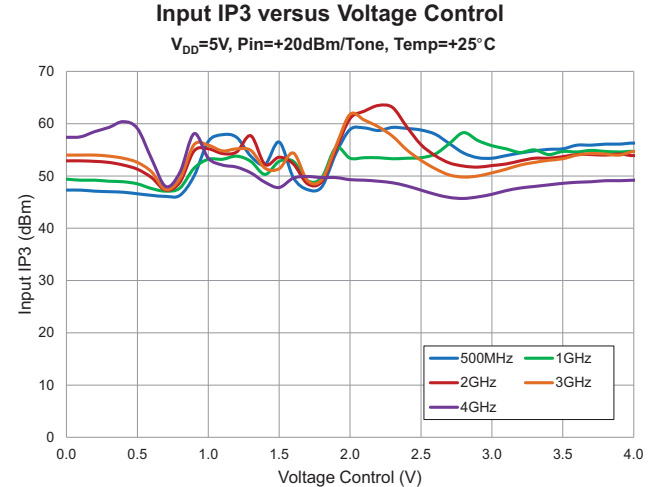
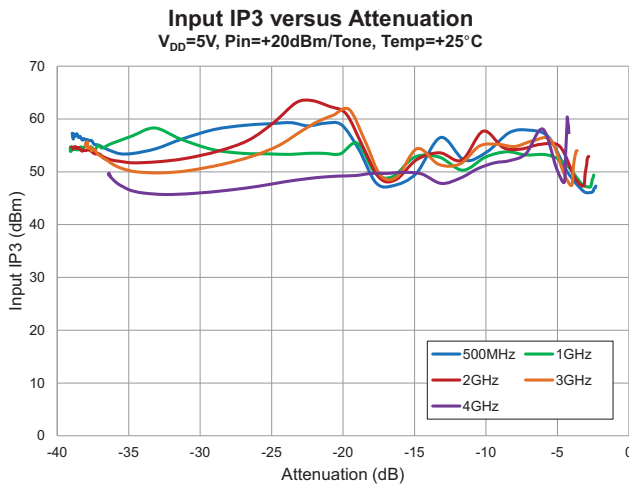
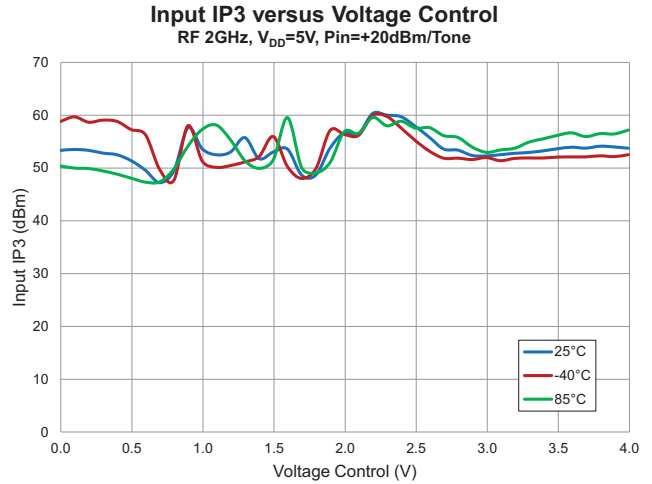
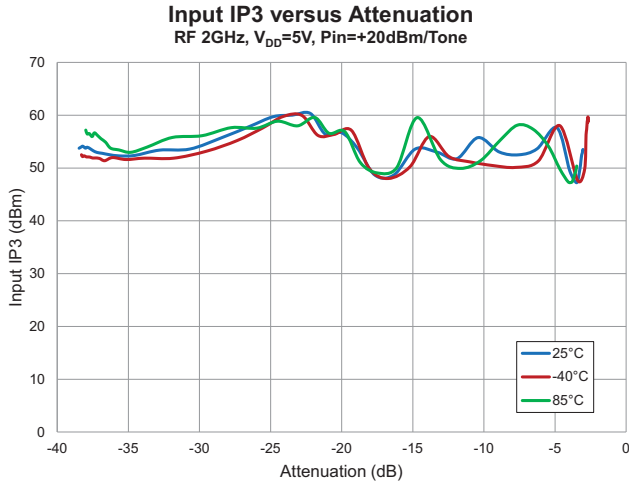


Output Return Loss versus Voltage Control
RF 2GHz, $V_{DD}=5V$



Measured Negative Attenuation Slope Performance

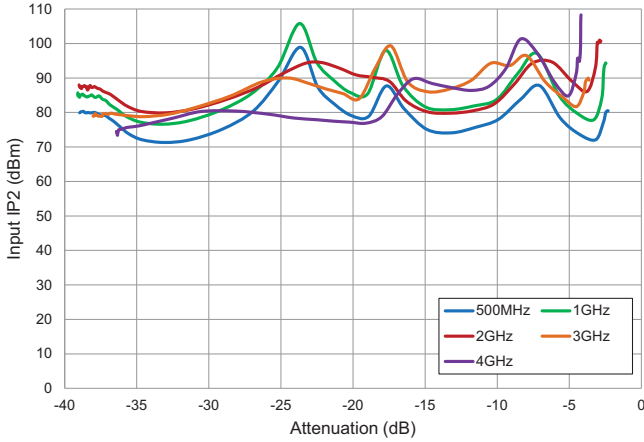
Data includes PCB and connector losses



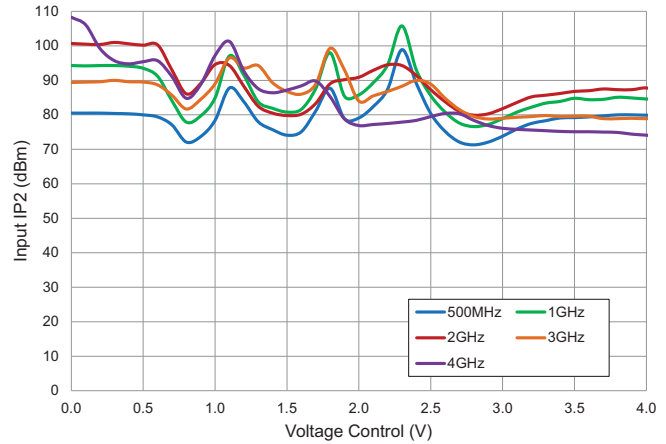
Measured Negative Attenuation Slope Performance

Data includes PCB and connector losses

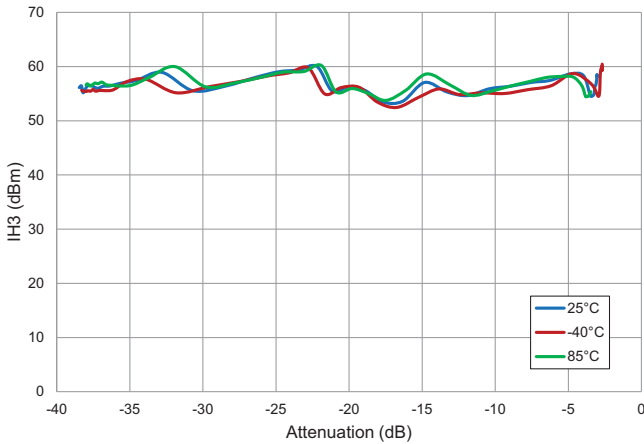
Input IP2 versus Attenuation
 $V_{DD}=5V$, $P_{in}=+20dBm/Tone$, $Temp=+25^{\circ}C$



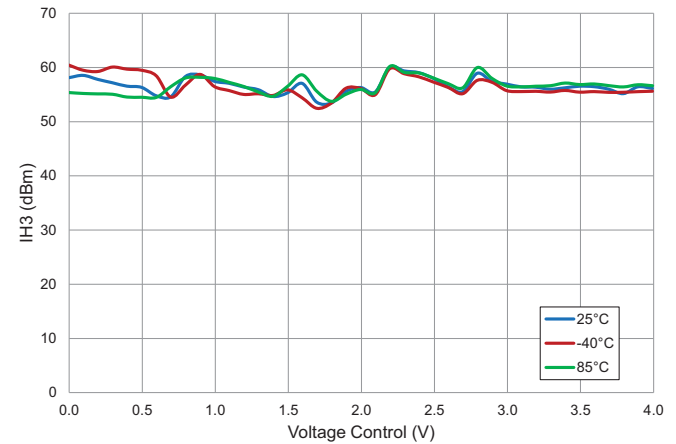
Input IP2 versus Voltage Control
 $V_{DD}=5V$, $P_{in}=+20dBm/Tone$, $Temp=+25^{\circ}C$



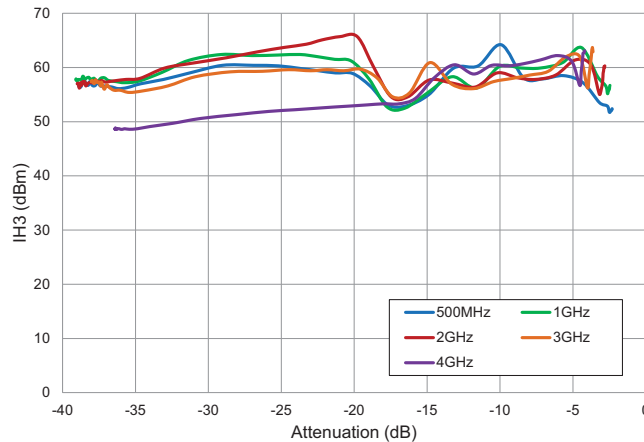
3rd Harmonic IH3 versus Attenuation
 RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm$



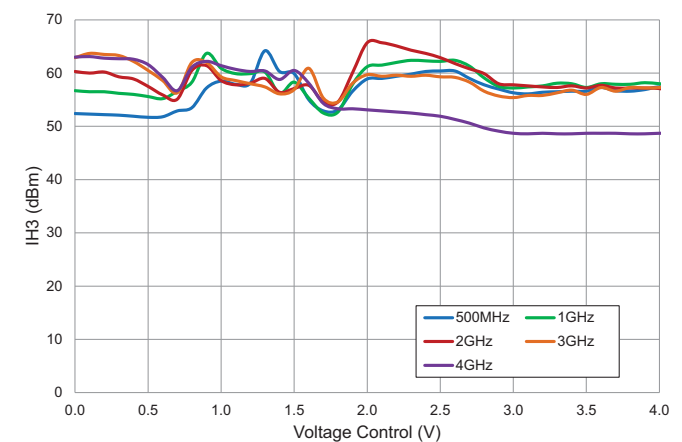
3rd Harmonic IH3 versus Voltage Control
 RF 2GHz, $V_{DD}=5V$, $P_{in}=+20dBm$



3rd Harmonic IH3 versus Attenuation
 $V_{DD}=5V$, $P_{in}=+20dBm$, $Temp=+25^{\circ}C$



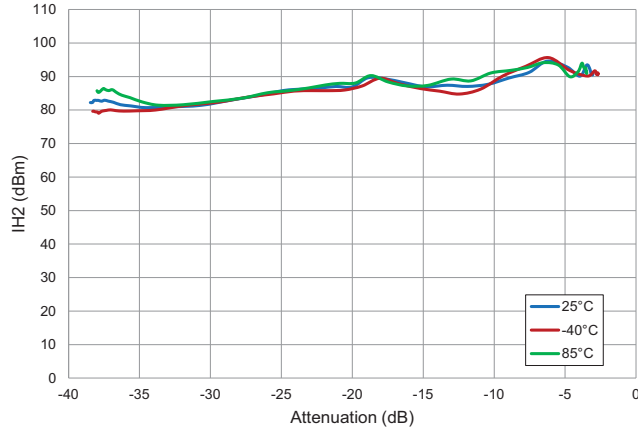
3rd Harmonic IH3 versus Voltage Control
 $V_{DD}=5V$, $P_{in}=+20dBm$, $Temp=+25^{\circ}C$



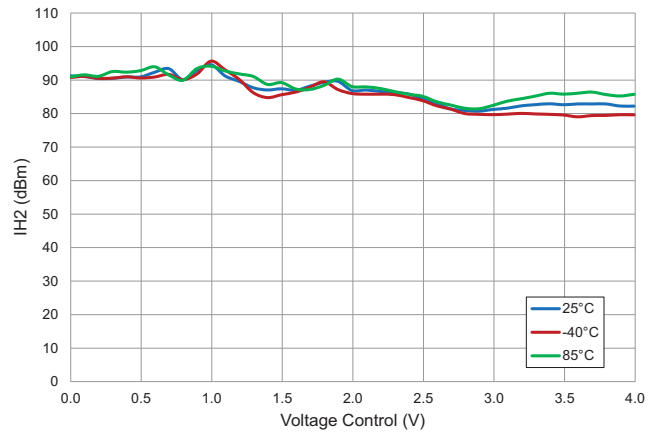
Measured Negative Attenuation Slope Performance

Data includes PCB and connector losses

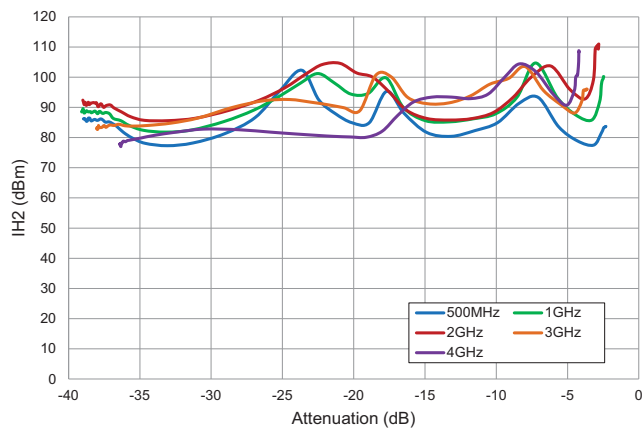
2nd Harmonic IH2 versus Attenuation
RF 2GHz, V_{DD}=5V, Pin=+20dBm



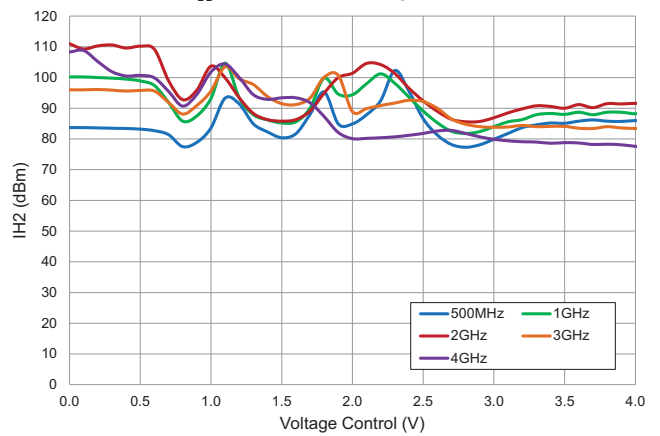
2nd Harmonic IH2 versus Voltage Control
RF 2GHz, V_{DD}=5V, Pin=+20dBm



2nd Harmonic IH2 versus Attenuation
V_{DD}=5V, Pin=+20dBm, Temp=+25°C



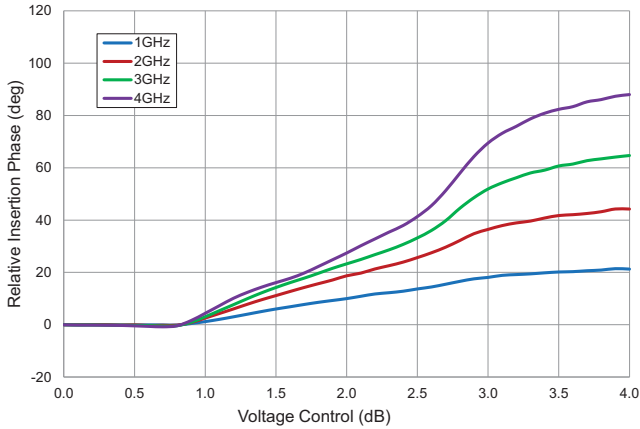
2nd Harmonic IH2 versus Voltage Control
V_{DD}=5V, Pin=+20dBm, Temp=+25°C



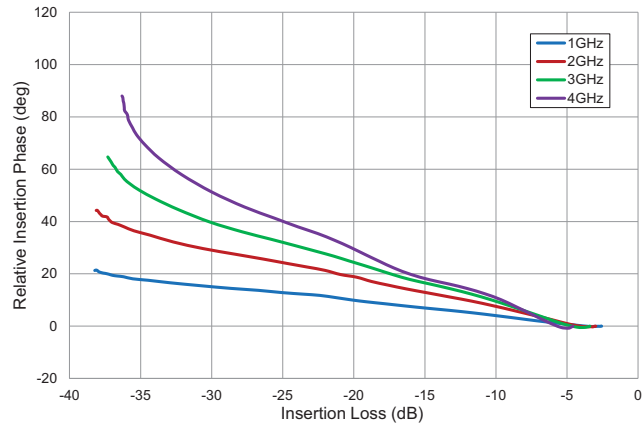
Measured Negative Attenuation Slope Performance

Data includes PCB and connector losses

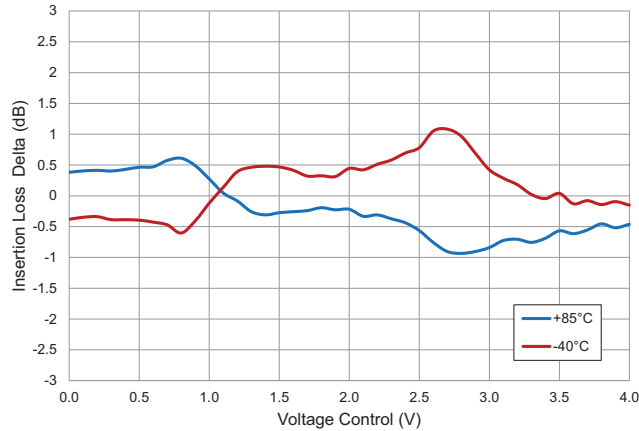
Relative Insertion Phase versus Voltage Control
RF 2GHz, $V_{DD}=5V$, Temp= $+25^{\circ}C$



Relative Insertion Phase versus Insertion Loss
RF 2GHz, $V_{DD}=5V$, Temp= $+25^{\circ}C$

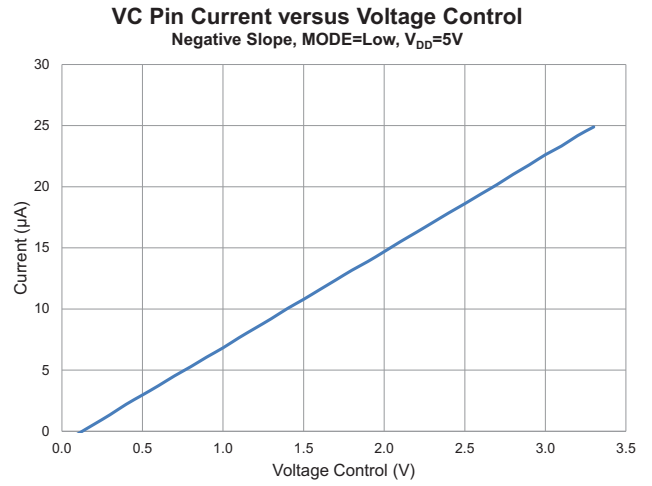
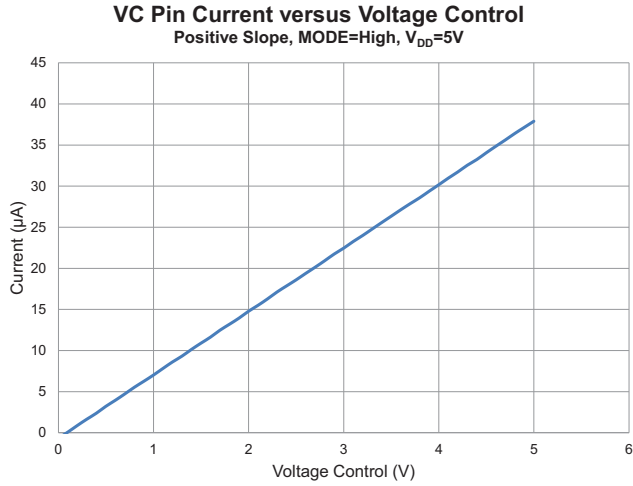


Insertion Loss Relative to $+25^{\circ}C$
RF 2GHz, $V_{DD}=5V$



Voltage Control Pin Current Performance

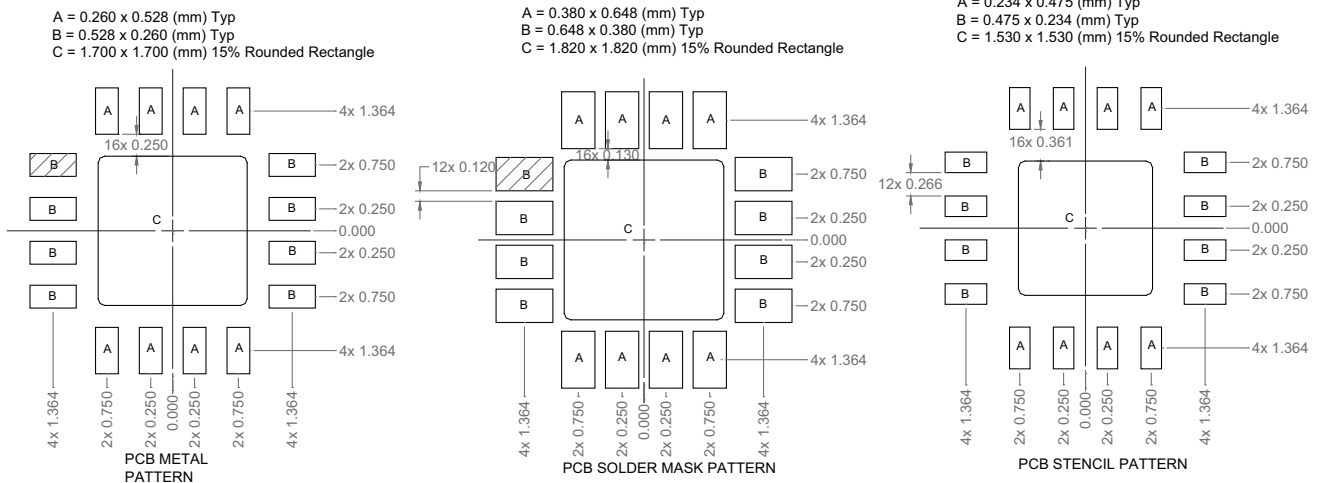
Data includes PCB and connector losses



Pin Names and Descriptions

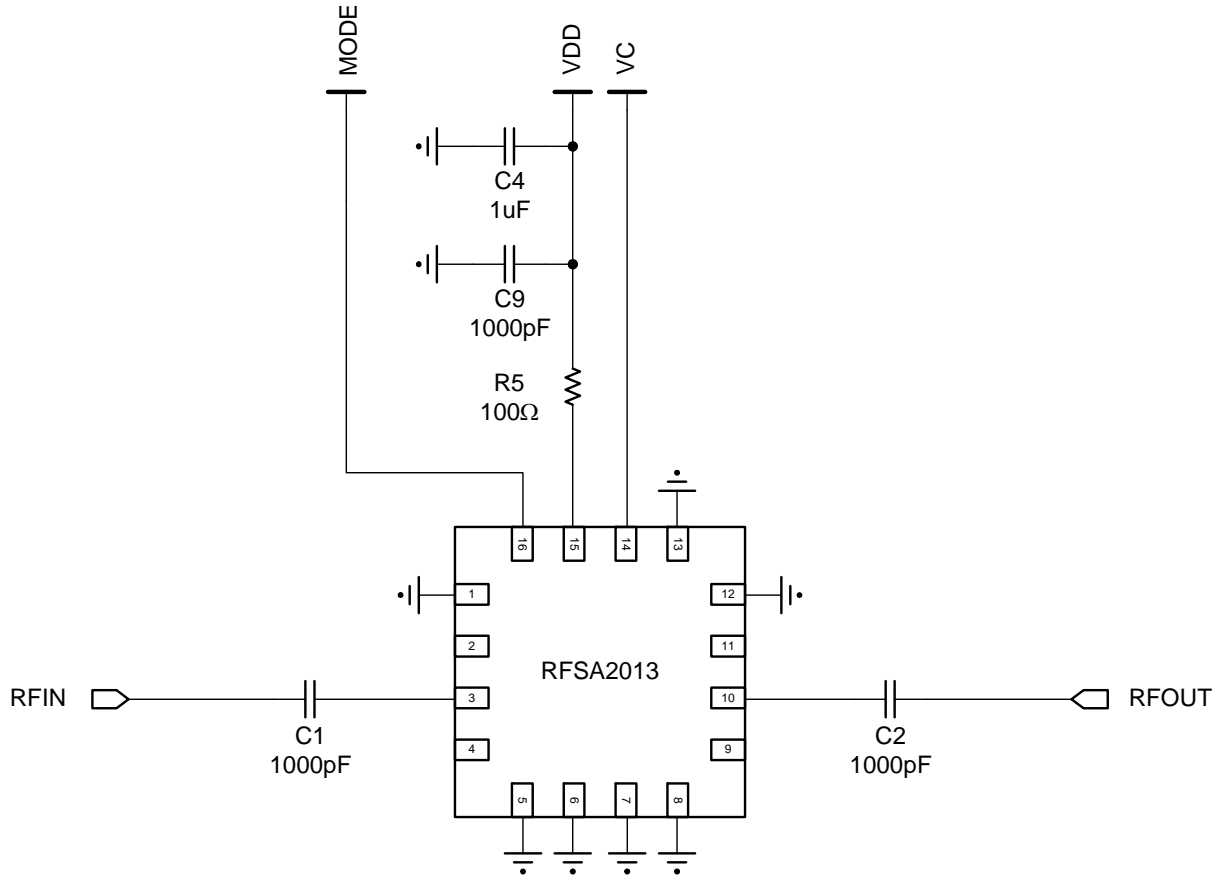
Pin	Name	Description
1	GND	Ground Pin
2	NC	No Connection. Do Not Connect to PC Board Ground Plane.
3	RFIN	RF Input. Use External DC Block. RF input must be this pin to insure linearity and thermal resistance specifications.
4	NC	No Connection. Do Not Connect to PC Board Ground Plane.
5	GND	Ground Pin
6	GND	Ground Pin
7	GND	Ground Pin
8	GND	Ground Pin
9	NC	No Connection. Do Not Connect to PC Board Ground Plane.
10	RFOUT	RF Output. Use External DC Block. RF output must be this pin to insure linearity and thermal resistance specifications.
11	NC	No Connection. Do Not Connect to PC Board Ground Plane.
12	GND	Ground Pin
13	GND	Ground Pin
14	VC	Attenuator Control Voltage
15	VDD	Supply Voltage (5V)
16	MODE	Attenuation Slope Control Set to Logic Low to Enable Negative Attenuation Slope. Set to Logic High to Enable Positive Attenuation Slope.
GND	GND	Exposed Package Ground Paddle is RF and DC Ground

PCB Patterns

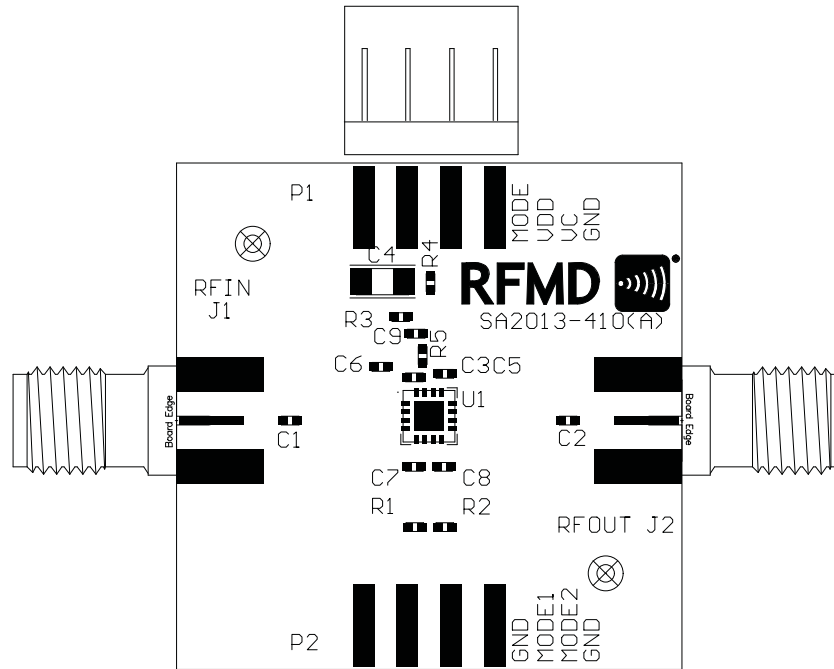


Thermal vias for center slug “C” should be incorporated into the PCB design. The number and size of thermal vias will depend on the application, the power dissipation and the electrical requirements. Example of the number and size of vias can be found on the RFMD evaluation board layout.

Evaluation Board Schematic



Evaluation Board Assembly Drawing



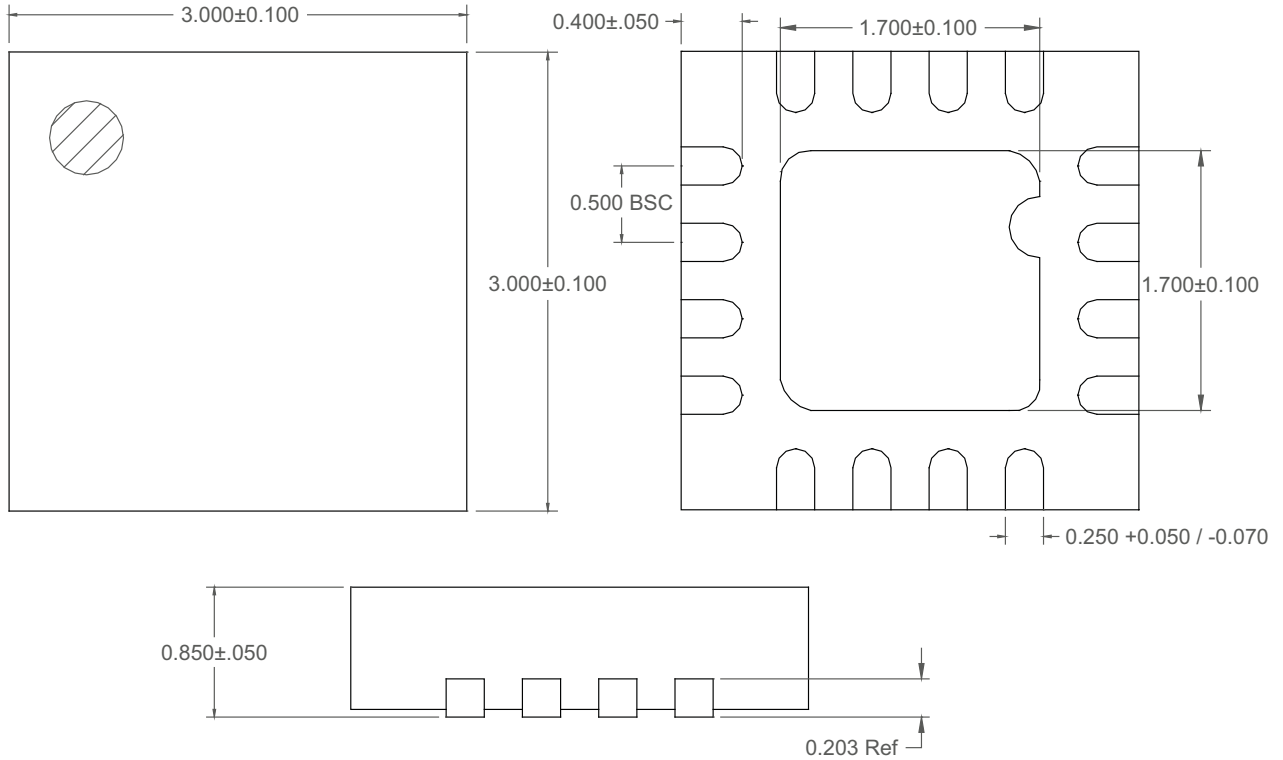
Evaluation Board Bill of Materials (BOM)

Description	Reference Designator	Manufacturer	Manufacturer's P/N
Voltage Controlled Attenuator VCA, 5V	U1	RFMD	RFSA2013
CONN, SMA, END LNCH, MINI, FLT, 0.068"	J1-J2	Emerson Network Power	142-0741-851
CONN, HDR, SR, 4-PIN, 0.100", T/H	P1	MOLEX	22-28-4043
PCB, SA2013-410		DDI	SA2013-410
CAP, 1000pF, 10%, 25V, X7R, 0402	C1-C2, C9	Murata Electronics	GRM155R71H102KA01D
CAP, 1μF, 10%, 16V, X7R, 1206	C4	Murata Electronics	GRM31MR71E105KC01L
RES, 100Ω, 5%, 1/16W, 0402	R5	Kamaya, Inc	RMC1/16S-101JTH
DNP	C3, C5-C8	N/A	N/A
DNP	R1-R4	N/A	N/A
DNP	P2	N/A	N/A

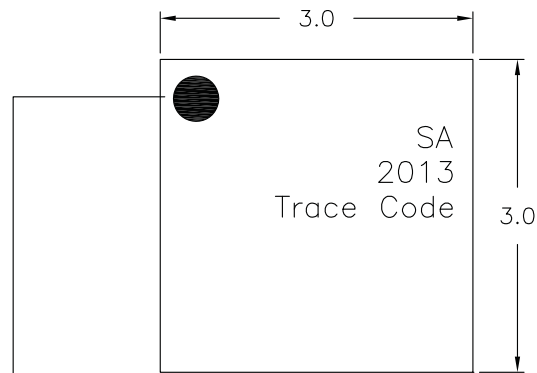
Notes:

1. Manufacturers' P/Ns are subject to change by the manufacturers following the issue of this document and are thereby included for reference only.
2. Contact RFMD Corporate Engineering Materials with questions regarding specific Manufacturers' P/Ns.

Package Drawing
(0.9mm x 3mm x 3mm)



Branding Diagram
(0.9mm x 3mm x 3mm)



Pin 1 Indicator
Trace Code to be assigned by SubCon